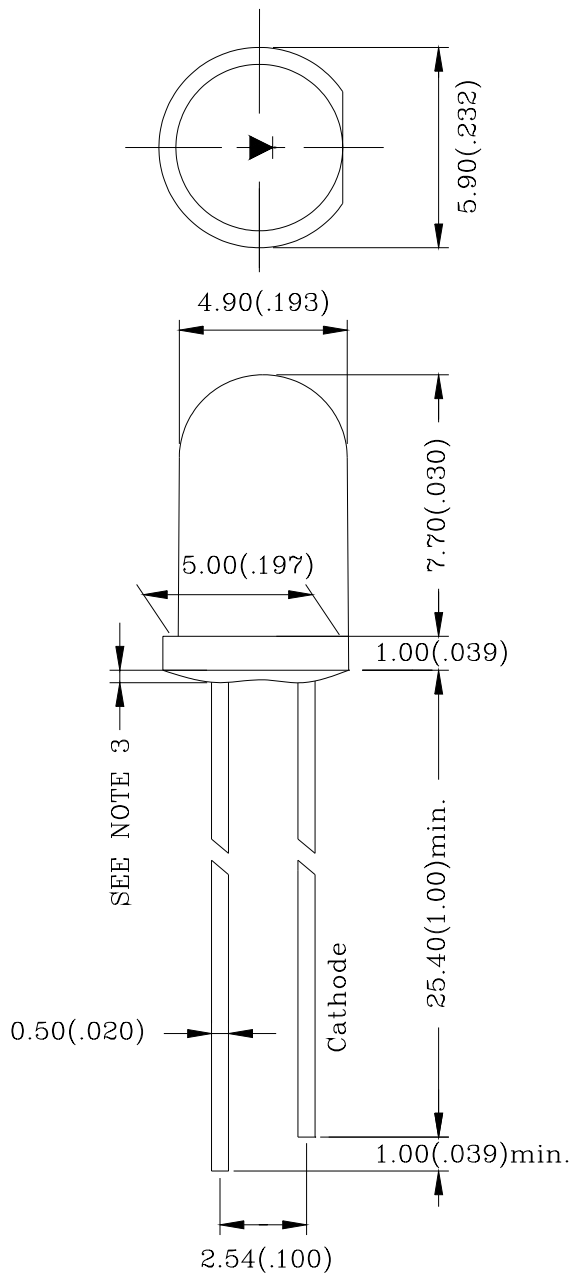


5.0 mm DIA LED LAMP

LED-560O2D

REV:A / 1

PACKAGE DIMENSIONS



Note:

1. All Dimensions are in millimeters.
2. Tolerance is $\pm 0.25\text{mm}$ (0.010 ") Unless otherwise specified.
3. Protruded resin under flange is 1.5mm (0.059 ") max.
4. Lead spacing is measured where the leads emerge from the package.
5. Specification are subject to change without notice

5.0 mm DIA LED LAMP

LED-56002D

REV:A / 1

FEATURES

- * 5.0mm DIA LED LAMP
- * HIGH LUMINOUS INTENSITY OUTPUT.
- * LOW POWER CONSUMPTION.
- * HIGH EFFICIENCY.
- * VERSATILE MOUNTING ON P.C. BOARD OR PANEL.
- * I.C. COMPATIBLE.

CHIP MATERIALS

- * Dice Material : GaAlInP/GaAs
- * Light Color : ULTRA ORANGE
- * Lens Color : ORANGE DIFFUSED

ABSOLUTE MAXIMUM RATING : (Ta = 25°C)

SYMBOL	PARAMETER	ULTRAORANGE	UNIT
PAD	Power Dissipation Per Chip	65	mW
VR	Reverse Voltage Per Chip	5	V
IAF	Continuous Forward Current Per Chip	25	mA
IPF	Peak Forward Current Per Chip (Duty – 0.1, 1KHz)	120	mA
—	Derating Linear From 25°C Per Chip	0.40	mA/°C
Topr	Operating Temperature Range	-25°C to 85°C	
Tstg	Storage Temperature Range	-40°C to 85°C	
Lead Soldering Temperature { 1.6mm(0.063 inch) From Body } 260°C ± 5°C for 5 Seconds			

ELECTRO-OPTICAL CHARACTERISTICS : (Ta = 25°C)

SYMBOL	PARAMETER	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
VF	Forward Voltage	IF = 20mA		2.0		V
IR	Reverse Current	VR = 5V			100	μA
λD	Dominant Wavelength	IF = 20mA		605		nm
Δλ	Spectral Line Half-Width	IF = 20mA		17		nm
2θ1/2	Half Intensity Angle	IF = 20mA		60		deg
IV	Luminous Intensity	IF = 20mA		400		mcd

5.0 mm DIA LED LAMP

LED-560O2D

REV:A / 1

